



Recent Advances in Memory Materials and Devices

Guest Editor:

Dr. Keyuan Ding

College of Materials Science and
Engineering, Shenzhen
University, Shenzhen 518055,
China

Deadline for manuscript
submissions:

closed (30 November 2023)

Message from the Guest Editor

Dear Colleagues,

Significant progress has been made in semiconductor memory, especially phase-change memory (PCM) based on heterostructure and superlattice structure materials, which have attracted considerable attention due to their excellent performance. Phase-change heterostructure (PCH) can overcome the low-precision bottleneck that limits multibit storage and parallel computing in conventional PCM, offering novel physical and chemical properties for semiconductor memory devices.

The development of a new heterostructure for PCM and ovonic threshold switch (OTS) is necessary for their emerging practical device applications. For instance, $\text{Sb}_2\text{Te}_3/\text{TiTe}_2$, the multilayer PCH architecture was designed for two-dimensional (2D) phase transitions in nanometer-thick Sb_2Te_3 phase-change material sublayers that are clamped by confinement TiTe_2 sublayers, enabling well-controlled cumulative/progressive SET (crystallization) and iterative/stepwise RESET (amorphization) operations.

We invite contributions of research articles and review on topics including but not limited to the theoretical calculation, synthesis, characterization, and application of novel heterostructures for PCM or OTS.





an Open Access Journal by MDPI

Editor-in-Chief

Message from the Editor-in-Chief

You are invited to contribute research articles or comprehensive reviews for consideration and publication in *Micromachines* (ISSN 2072-666X). *Micromachines* is published in the open access format. Research articles, reviews and other contents are released on the internet immediately after acceptance. The scientific community and the general public have unlimited free access to the content as soon as it is published. As an open access journal, *Micromachines* is supported by the authors or their institutes by payment of article processing charges (APC) for accepted papers. We are pleased to welcome you as our authors.

Author Benefits

Open Access: free for readers, with article processing charges (APC) paid by authors or their institutions.

High Visibility: indexed within Scopus, SCIE (Web of Science), PubMed, PMC, Ei Compendex, dblp, and other databases.

Journal Rank: JCR - Q2 (Instruments and Instrumentation) / CiteScore - Q1 (Mechanical Engineering)

Contact Us

Micromachines Editorial Office
MDPI, Grosspeteranlage 5
4052 Basel, Switzerland

Tel: +41 61 683 77 34
www.mdpi.com

mdpi.com/journal/micromachines
micromachines@mdpi.com
[X@micromach_mdpi](https://twitter.com/micromach_mdpi)